

Code No: R21026 (R10) (SET - 1)

## II B. Tech I Semester Supplementary Examinations, May/June - 2017 ELECTRONIC DEVICES AND CIRCUITS

(Com. to EEE, ECE, EIE, ECC, CSE, IT, BME)

Time: 3 hours Max. Marks: 75

## Answer any **FIVE** Questions All Questions carry **Equal** Marks

- 1. a) Explain about in magnetic field.
  - b) A charged particle having charge thrice that of an electron and mass twice that of an electron is accelerated through a potential difference of 50V before it enters a uniform magnetic field flux density of 0.02 Wb/m<sup>2</sup> at an angle of 25° with field.

Calculate i). The velocity of the charged particle before entering the field.

- ii). Radius of the helical path
- iii) Time of revolution.

(5M+10M)

- 2. a) In a p-type semiconductor, the Fermi level is  $0.25 \omega$  above the valence band at room temperature of  $300^{0}$ K. Determine the new position of Fermi level when the temperatures are i)  $400^{0}$ K ii)  $600^{0}$ K
  - b) Define Drift and diffusion currents in semiconductor.

(8M + 7M)

- 3. a) Explain the principle behind the Varactor diode and list out its applications.
  - b) Explain the Construction of a PIN diode and give the applications of PIN diode. (7M+8M)
- 4. a) Explain about series and shunt voltage regulators.
  - b) Derive an expression for the ripple factor in a full wave rectifier using inductor filter.

(7M+8M)

- 5. a) A transistor has  $I_B = 100 \mu A$  and  $I_C = 2 \mu A$  Find
  - i)  $\beta$  of the transistor ii)  $\alpha$  of the transistor iii) Emitter current  $I_E$
  - iv) if  $I_B$  changes by +25 $\mu$ A and  $I_C$  changes by +0.6mA. Find the new valve of  $\beta$ ?
  - b) Explain about Photo Transistor.

(5M+10M)

- 6. a) Explain the construction and working of n-channel JFET?
  - b) Briefly describe some applications of JFET.

(10M+5M)

- 7. a) Explain in detail about Stabilization factors.
  - b) Explain about Thermistor and Sensistor compensation.

(7M+8M)

- 8. a) Explain about Conversion formulas for the parameters of three transistor configuration
  - b) Explain in detail about Measurement of h-parameters

(7M+8M)

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